

PROCEEDINGS OF SPIE

Organic and Hybrid Field-Effect Transistors XX

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Editors

1-5 August 2021
San Diego, California, United States

Sponsored and Published by
SPIE

Volume 11811

Proceedings of SPIE 0277-786X, V. 11811

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Organic and Hybrid Field-Effect Transistors XX, edited by Iain McCulloch,
Oana D. Jurchescu, Proc. of SPIE Vol. 11811, 1181101 · © 2021 SPIE
CCC code: 0277-786X/21/\$21 · doi: 10.1117/12.2606638

Proc. of SPIE Vol. 11811 1181101-1

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Author(s), "Title of Paper," in *Organic and Hybrid Field-Effect Transistors XX*, edited by Iain McCulloch, Oana D. Jurchescu, Proc. of SPIE 11811, Seven-digit Article CID Number (DD/MM/YYYY); (DOI URL).

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781510644601

ISBN: 9781510644618 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time)

SPIE.org

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